A Novel L-Z Source Inverter with Improving of Classical Z Source Inverter

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Abstract: On the basis of the classical ZSI(Z source inverter) provides a common ground for the DC source and Inverter, and avoids the disadvantages caused by capacitor in the Classical ZSI and SL-ZSI, especially in prohibiting the inrush current at startup. The inverter uses a unique inductor and diode network for boosting its output voltage. This inverter can improve the boost factor through adjusting shoot-through duty ratio and increasing the number of inductors. This thesis presents a novel ZSI uses a unique inductor and diode network with reducing inrush current. The working principle experimental results are analyzed in detail.

Keywords: Inrush Current, Resonance, Inductor, Power converter

1. Introduction

Z-source inverter is a type of power inverter, a circuit that converts direct current to alternating current. It functions as a buck-boost inverter without making use of Dc-Dc Converter Bridge due to its unique circuit topology. Impedance Z-source networks provide an efficient means of power conversion between source and load in a wide range of electric power conversion applications. The DC source is not always constant, such as a fuel cell, photo voltaic array and during voltage sags etc. a DC/DC boost converter is often needed to boost the DC voltage to meet the required output voltage or to allow the nominal operating point to be favorably located. This increases the system complexity and is desirable to eliminate if possible. This problem can be overcome by Z-source inverters in single-stage operations.

In recent years, various Z-source inverter (ZSI) topologies have been presented in numerous diversified studies[1-13]. Some of the studies are focused on applications, modeling, controls and modulation strategies [1-9], whereas others are focused on the development of new topologies [10-13].

The ZSIs accomplish a single-stage power conversion with buck-boost capabilities. In ZSIs, both of the power switches in a leg can be turned on at the same time and thereby eliminate the dead time. This significantly improves the reliability and reduces the output waveform distortion. Fig. 1(a) shows the classical ZSI in which the two-port impedance network couples the main inverter circuit to the dc source. In order to overcome the shortcomings of the classical ZSI, the quasi-ZSI (QZSI) shown in Fig. 1(b) and SL-ZSI shown in Fig. 1(c) [10, 11, 12]. Despite the aforementioned merits, the aforementioned Z-source inverter topologies also show the following drawbacks: 1) capacitors are used in the Z-source network, thus high-voltage or large capacity capacitors should be used, which may result in large volume, cost expensive, and reducing the life span of system; 2) it cannot suppress the inrush current and the resonance introduced by Z-source capacitators and inductors at startup, thus causing the voltage and current surge, which may destroy the devices; 3) it regulates boost factor only by adjusting the shoot-through duty ratio. To solve the aforesaid drawbacks in aforementioned Z-source inverter, a new Z-source inverter topology is presented with no capacitor and reducing inherent inrush current limitation at startup.

2. L- Z- Source Inverter

Different to the original ZSI, the proposed inverter has no capacitor, and is composed of two inductors (L1, L2, and L1=L2), and three diodes (D1, D2, and D3), as shown in Fig.2. The combination of L2– L3– D1– D2– D3 acts as a switched inductor cell [12- 13]. The proposed topology provides inrush current suppression, unlike the traditional topologies, because no current flows to the main circuit at startup. The proposed topology also provides a common ground for the source and inverter.
A. Operation Principles

Unlike the traditional ZSI, L-ZSI just has shoot-through zero states besides the traditional six active states. The operating principles of the proposed inverter are also similar to those of the classical ZSI. For the purpose of analysis, the operating states are simplified into shoot-through and non-shoot-through states. Fig. 3 shows the equivalent circuits of L-ZSI.

In the nonshoot-through state, as shown in Fig. 2, D2 is on, while D1 and D3 are off. L1 and L2 (L1 = L2 = L) are connected in series. L1 and L2 transfer energy from the dc voltage source to the main circuit, and the equivalent circuit is shown in Fig. 3(a). The corresponding voltages across L1 and L2 in this state are \( V_{a_{\text{nonshoot}}} \) and \( V_{b_{\text{nonshoot}}} \), respectively. Thereby, (1) and (2) can be contained.

\[
V_{a_{\text{nonshoot}}} + V_{b_{\text{nonshoot}}} + V_i = V_d \quad (1)
\]
\[
V_{a_{\text{nonshoot}}} = V_{b_{\text{nonshoot}}} \quad (2)
\]

From (1) & (2) we get, (3) & (4),
\[
V_{a_{\text{nonshoot}}} = \frac{1}{2}V_d - \frac{1}{2}V_i = V_{b_{\text{nonshoot}}} \quad (3) & (4)
\]

Where \( V_d \) is the DC source; \( V_i \) is the dc link voltage.

In the shoot-through state, as shown in Fig. 2, the inverter side is shorted by both the upper and lower switching devices of any phase leg. During the shoot-through state, D2 is off, while D1 and D3 are on. L1 and L2 are connected in parallel, and inductors L1 and L2 store energy. The equivalent circuit is shown in Fig. 3(b). The corresponding voltages across L1 and L2 in this state are \( V_1 \) and \( V_2 \), respectively, and (5) is obtained

\[
V_a = V_b = V_d \quad (5)
\]

Applying the volt-second balance principle to \( L_i \) and \( L_2 \), (6), (7), (8) and (9) can be obtained from (3), (4), and (5).

\[
\frac{1}{2}V_d - \frac{1}{2}V_i = V_{a_{\text{nonshoot}}} \quad (3) & (4)
\]

A. Boost Ability and Stress Comparison

Different control and load conditions provide varied stresses of impedance-type power inverters. For comparison, the proposed L-ZSI, SL-ZSI, and the classical ZSI are simplified, as shown in Fig. 6. The ac side circuit is represented by its simplified equivalent dc load [20]. A resistive load impedance (\( R_l \)) connects directly in parallel with active switch \( S \), where \( i_l \) and \( v_l \) are the instantaneous load current and voltage.
Table 1: Stress Comparison in the Case of the Same D AND Vd

<table>
<thead>
<tr>
<th>Parameter</th>
<th>SL-ZSI</th>
<th>Classical ZSI</th>
<th>L-ZSI</th>
</tr>
</thead>
<tbody>
<tr>
<td>$B$</td>
<td>$(1 + D)/(1 - 3D)$</td>
<td>$1/(1 - 2D)$</td>
<td>$1 + (n - 1)D/1 - D$</td>
</tr>
<tr>
<td>$V_s$</td>
<td>$(1 + D)V_{dc}/(1 - 3D)$</td>
<td>$(1 - D)V_{dc}/(1 - 2D)$</td>
<td>$0$</td>
</tr>
<tr>
<td>$V_c$</td>
<td>$(1 + D)V_{dc}/(1 - 3D)$</td>
<td>$V_{dc}/(1 - 2D)$</td>
<td>$1 + (n - 1)D/1 - D - V_{dc}$</td>
</tr>
<tr>
<td>$I_L$</td>
<td>$(1 - D)(1 + D)V_{dc}/(1 - 3D)$</td>
<td>$(1 - D)V_{dc}/(1 - 2D)$</td>
<td>$R_i$</td>
</tr>
<tr>
<td>$I_C$</td>
<td>$(1 - D)^2(1 + D)V_{dc}/(1 - 3D)^2$</td>
<td>$(1 - D)^2V_{dc}/(1 - 2D)^2$</td>
<td>$R_i(1 - D)$</td>
</tr>
</tbody>
</table>

(Where $V_c$ is capacitor voltage in Z-source network, and $V_s$ is voltage stress of switching device.)

Compared with the classical ZSI and SL-ZSI, the proposed inverter can increase the voltage boost inversion ability through adjusting short shoot-through duty ratio or the number of inductor as shown in Fig.7. From Fig.7, it can be seen that voltage gain is increased with the increasing of shoot-through Duty ratio and the increasing of the number of inductors.

Since there is no capacitor in L-ZSI, capacitor voltage stress is zero. In SL-ZSI and the classical ZSI, capacitor voltage stress is increased with the increasing of voltage gain.

In classical ZSI, SL-ZSI, and L-ZSI, the voltage stress $V_s$ across the switches is just determined by dc link voltage $V_{dc}$ as shown in Tab.1, and Fig.10 shows the switching device voltage stress curves. So, the voltage stress $V_s$ is the same in classical ZSI, SL-ZSI, and L-ZSI with same boost factor. That is to say the voltage stress $V_s$ is also the same in classical ZSI, SL-ZSI, and L-ZSI, when the voltage gain and modulation index are the same.

Fig.6 shows the boost factor comparison among the classical ZSI, SL-ZSI, and L-ZSI. In Fig.8, through adjusting the number of inductors, the boost factor of L-ZSI can be larger than that of SL-ZSI and the classical ZSI with short shoot-through zero states. Average value for boost factor change rate of L-ZSI is far less than that of SL-ZSI and the classical ZSI. This characteristic makes the boost factor change of L-ZSI is not very large, when the shoot-through duty ratio is changed. This characteristic also makes the control of L-ZSI is easier than that of SL-ZSI and the classical ZSI, when the shoot-through duty ratio is near 0.3 for SL-ZSI and near 0.5 for classical ZSI.

Fig.9 and Fig.10 show the inductor current stress in the classical ZSI, SL-ZSI, and L-ZSI. In Fig.11, it shows the inductor current stress of SL-ZSI and L-ZSI under different n. The inductor current stress of L-ZSI is increased with the increasing of shoot-through duty ratio and the increasing of the number of inductor. Comparing Fig.11 and Fig.8, The inductor current stress of L-ZSI is smaller than that of SL-ZSI, when the boost factor is equal to each other. Tab. 2 shows the inductor current stress comparison between L-ZSI and SL-ZSI, when the boost factor is equal to each other. Comparing Fig.12 and Fig.8, The inductor current stress of L-ZSI is smaller than that of the classical ZSI, when the boost factor is equal to each other. Tab. 3 shows the inductor current stress comparison between L-ZSI and the classical ZSI, when the boost factor is also equal to each other.
Figure 10: Inductor current stress comparison between L-ZSI and the classical ZSI.

Table 2: Inductor Current Stress Comparison between L-ZSI and SL ZSI

<table>
<thead>
<tr>
<th>Boost factor</th>
<th>D</th>
<th>L-ZSI n=5</th>
<th>L-ZSI n=6</th>
<th>L-ZSI n=7</th>
<th>SL-ZSI</th>
</tr>
</thead>
<tbody>
<tr>
<td>1.5</td>
<td>1/11</td>
<td>1.5(V_{dc}/R_l)</td>
<td>1.7(V_{dc}/R_l)</td>
<td></td>
<td></td>
</tr>
<tr>
<td>2</td>
<td>1/7</td>
<td>2(V_{dc}/R_l)</td>
<td>2.6(V_{dc}/R_l)</td>
<td></td>
<td></td>
</tr>
<tr>
<td>2.5</td>
<td>3/17</td>
<td>2.5(V_{dc}/R_l)</td>
<td>3.6(V_{dc}/R_l)</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

Table 3: Inductor Current Stress Comparison between L-ZSI and the Classical ZSI

<table>
<thead>
<tr>
<th>Boost factor</th>
<th>D</th>
<th>L-ZSI n=3</th>
<th>L-ZSI n=4</th>
<th>L-ZSI n=5</th>
<th>traditional ZSI</th>
</tr>
</thead>
<tbody>
<tr>
<td>2</td>
<td>1/4</td>
<td>2(V_{dc}/R_l)</td>
<td></td>
<td></td>
<td>2.25(V_{dc}/R_l)</td>
</tr>
<tr>
<td>3</td>
<td>1/3</td>
<td>3(V_{dc}/R_l)</td>
<td></td>
<td></td>
<td>4(V_{dc}/R_l)</td>
</tr>
<tr>
<td>4</td>
<td>3/8</td>
<td>4(V_{dc}/R_l)</td>
<td></td>
<td></td>
<td>6.25(V_{dc}/R_l)</td>
</tr>
</tbody>
</table>

B. Inrush Current and Voltage Overshoot Analysis

The Z-source impedance network is the energy storage and filtering element for the ZSI. The purpose of the inductors is to limit the current ripples through the devices during boost mode with the shoot- through state. Moreover, the purpose of the capacitors is to absorb the current ripples and maintain a constant voltage to keep the ac output voltage sinusoidal.

Figure 11: Startup equivalent circuit for the classical ZSI and SL-ZSI.

3. Results

To verify the aforementioned theoretical results, Simulation examples for L-ZSI are given using MATLAB/SIMULINK using the maximum boost control method [20].

1) \(L_1 = L_2 = \ldots = L_n = L = 45\mu H\);
2) three-phase output filter: \(L_f = 1mH, C_f = 22\mu F\);
3) Switching frequency \(f_s = 10\ kHz\);
4) three-phase balanced resistive load, \(R_l = 10\ O\);
5) Snubber circuit: \(R_s = 20k, C_s = 0.1\mu F/100V\).

A. Simulation Result I

This example is the voltage inversion from dc 48 V to ac 35Vrms and \(n=2\). Assuming D=0.2 and M=0.8, B=1.5.

\(V_{ac} = MB V_{dc}/2 = 28.8V\)

\(V_{ac}\) is the phase peak voltage, which implies that the Line-to-line voltage is 35Vrms or 50 V peak.

Fig.12 shows the simulation results. From fig.12, it can be seen that the above theoretical values are quite consistent with the simulation results.

Figure 12: Simulation output results

4. Conclusion

This thesis has proposed a novel L-ZSI with improving classical ZSI. This system operates based Permanent Magnet Brushless DC motor drive. This drive system has the advantages of both PMBDCM and Z-source inverter. The system configuration, operation principle and control method have been analyzed in detail. And based on the equivalent circuits, the mathematical model has been established by state-space averaging method. Simulation results have validated the preferred features as well as the possibility of the proposed drive system. Additionally, the shortcoming of switching loss has been discussed, and a possible improvement method has been presented. Based on this...
system the inrush current at startup can be completely eliminated.

5. Future Scope

Through the above analysis, it can be known that switched-inductor cell can improve the voltage gain, based on this feature the Z-source network can be extended. The operating principles as follows

In the non-shoot-through state, $D_{1,2}, D_{2,2}, \ldots, D_{n-1,2}$ and $D_{n,2}$ are on, while $D_{1,1}, D_{1,3}, D_{2,1}, D_{2,3}, \ldots, D_{n-1,1}, D_{n-1,3}, D_{n,1}$ and $D_{n,3}$ are off. $L_1, L_2, \ldots, L_{n-1}$ and $L_n$ are connected in series. $L_1, L_2, \ldots, L_{n-1}$ and $L_n$ transfer energy from the dc voltage source to the main circuit. The corresponding voltages across $L_1, L_2, \ldots, L_{n-1}$ and $L_n$ in this state are $V_{1_{\text{non}}}, V_{2_{\text{non}}}, V_{3_{\text{non}}}, \ldots, V_{n_{\text{non}}}$, respectively.

In the shoot-through state, the inverter side is shorted by both the upper and lower switching devices of any phase leg. During the shoot-through state, $D_{1,2}, D_{2,2}, \ldots, D_{n-1,2}$ and $D_{n,2}$ are off, while $D_{1,1}, D_{1,3}, D_{2,1}, D_{2,3}, \ldots, D_{n-1,1}, D_{n-1,3}, D_{n,1}$ and $D_{n,3}$ are on. $L_1, L_2, \ldots, L_{n-1}$ and $L_n$ are connected in parallel, inductors $L_1, L_2, \ldots, L_{n-1}$ and $L_n$ store energy is obtained.

Applying the volt-second balance principle to each inductor,

$\bar{V}_1 = \bar{V}_2 = \cdots = \bar{V}_{n-1} = \bar{V}_n = V_{dc}$

When the load is resistive, is concluded, as follows.

In view of boost factor, the boost factor of L-ZSI is $[1+(n-1)D]/(1-D)$. When $n=2$, the boost factor of L-ZSI is $(1+D)/(1-D)$ which is different from that of SL-ZSI. When $n=1$, the boost factor of L-ZSI is $1/(1-D)$ which is different from that of classical ZSI, and the boost voltage feature of L-ZSI is just like that of traditional boost converter at this time. The boost factor of L-ZSI is increased with the increasing number of inductors, and the number of inductors is not limited. The range of D is $[0, 1)$. The boost factor of the voltage-type SL Z-Source Inverter proposed in [13] is $(1+nD)/(1-(n+2)D)$. When $n=1$, the boost factor of the voltage-type SL Z-Source Inverter is $(1+D)/(1-3D)$ which is the same as that of SL-ZSI, and the topology is also the same as that of SL-ZSI at this time. When $n=0$, the boost factor of the voltage-type SL Z-Source Inverter is $1/(1-2D)$ which is the same as that of classical ZSI, and the topology is also the same as that of classical ZSI at this time. In the voltage-type SL Z-Source Inverter, the number of inductors and the range of D are limited by $1-(n+2)D>0$, namely, $n <1/D-2$ and $D<0.5$. Through the above analysis, there is no resemblance between the proposed L-ZSI and the voltage-type SL Z-Source Inverter both in principle and operation.

References


Author Profile

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